

**PECL and LVDS Low Phase Noise VCXO (for 65-130MHz Fund Xtal)**

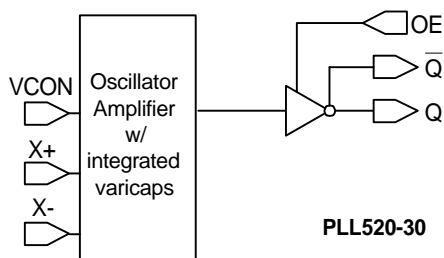
**FEATURES**

- 65MHz to 130MHz Fundamental Mode Crystal.
- Output range: 65MHz – 130MHz (no PLL).
- Low Injection Power for crystal 50uW.
- Complementary outputs: PECL or LVDS.
- Integrated variable capacitors.
- Supports 3.3V-Power Supply.
- Available in die form.
- Thickness 10 mil.

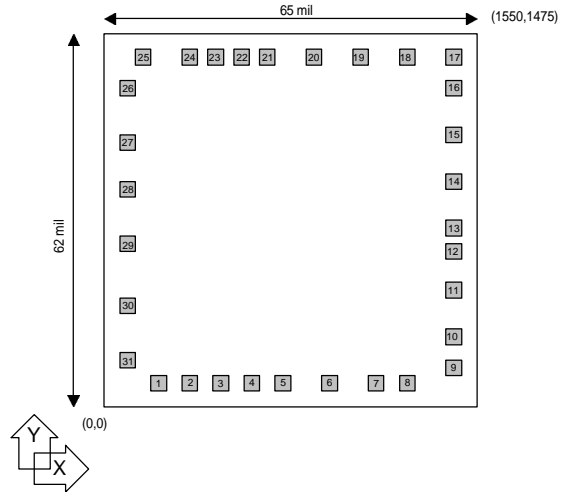
**DESCRIPTIONS**

PLL520-30 is a VCXO IC specifically designed to pull frequency fundamental crystals from 65MHz to 130MHz, with selectable PECL or LVDS outputs. Its design was optimized to tolerate higher limits of interelectrodes capacitance and bonding capacitance to improve yield. It achieves very low current into the crystal resulting in better overall stability. Its internal varicaps allow an on chip frequency pulling, controlled by the VCON input.

**BLOCK DIAGRAM**



**DIE CONFIGURATION**



**DIE SPECIFICATIONS**

Name	Value
Size	62 x 65 mil
Reverse side	GND
Pad dimensions	80 micron x 80 micron
Thickness	10 mil

**OUTPUT SELECTION AND ENABLE**

Pad #9 OUTSEL	Selected Output
0	LVDS
1	PECL (default)

Pad #9 OUTSEL	Pad #30 OE_CTRL	State
0	0	Tri-state
	1	Output enabled (default)
1	0	Output enabled (default)
	1	Tri-state

Pad #9 and #30: Bond to GND to set to "0", bond to VDD to set to "1"  
 Pad #30: Logical states defined by PECL levels if OUTSEL (pad #9) is "1"  
 Logical states defined by CMOS levels if OUTSEL (pad #9) is "0"

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**ELECTRICAL SPECIFICATIONS**
**1. Absolute Maximum Ratings**

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	$V_{DD}$		7	V
Input Voltage, dc	$V_I$	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Output Voltage, dc	$V_O$	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Storage Temperature	$T_S$	-65	150	°C
Ambient Operating Temperature*	$T_A$	-40	85	°C
Junction Temperature	$T_J$		125	°C
Lead Temperature (soldering, 10s)			260	°C
Input Static Discharge Voltage Protection			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

\* **Note:** Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for INDUSTRIAL grade only.

**2. Crystal Specifications**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Built-in Capacitance	CX+	65MHz to 130MHz (VDD=3.3V)			2	pF
	CX-				2	
Inter-electrode capacitance	$C_0$			2.6		
C0/C1 ratio (gamma)	$\gamma$				300	-
Oscillation Frequency	OF	Fund.	65		130	MHz

**3. Voltage Control Crystal Oscillator**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
VCXO Stabilization Time *	$T_{VCXOSTB}$	From power valid		10		ms
VCXO Tuning Range		XTAL $C_0/C_1 < 300$	200*			ppm
CLK output pullability		$0V \leq VCON \leq 3.3V$ at room temperature		$\pm 100^*$		ppm
On-chip Varicaps control range		$VCON = 0$ to 3.3V		4 – 18*		pF
Linearity				5*	10*	%
VCXO Tuning Characteristic				65		ppm/V
VCON input impedance				60		k $\Omega$
VCON modulation BW		$0V \leq VCON \leq 3.3V, -3dB$	25			kHz

**Note:** Parameters denoted with an asterisk (\*) represent nominal characterization data and are not production tested to any specific limits.

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**4. General Electrical Specifications**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current (Loaded Outputs)	I <sub>DD</sub>	PECL/LVDS			100/80	mA
Operating Voltage	V <sub>DD</sub>		3.13		3.47	V
Output Clock Duty Cycle		@ 1.25V (LVDS) @ V <sub>dd</sub> - 1.3V (PECL)	45 45	50 50	55 55	%
Short Circuit Current				±50		mA

**5. Jitter specifications**

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period jitter RMS	77.76MHz		3.5*		ps
Period jitter peak-to-peak	77.76MHz		24*		ps
Integrated jitter RMS	Integrated 12 kHz to 20 MHz at 77.76MHz		0.5*		ps

\*: To be measured

**6. Phase noise specifications**

PARAMETERS	FREQUENCY	@10Hz	@100Hz	@1kHz	@10kHz	@100kHz	UNITS
Phase Noise relative to carrier	77.76MHz	-75	-95	-125	-145	-155	dBc/Hz

Note: Phase Noise at VCON = 0V – to be measured

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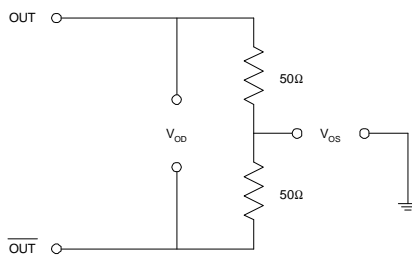
**7. LVDS Electrical Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	$V_{OD}$	$R_L = 100 \Omega$ (see figure)	247	355	454	mV
$V_{DD}$ Magnitude Change	$\Delta V_{OD}$		-50		50	mV
Output High Voltage	$V_{OH}$			1.4	1.6	V
Output Low Voltage	$V_{OL}$		0.9	1.1		V
Offset Voltage	$V_{OS}$		1.125	1.2	1.375	V
Offset Magnitude Change	$\Delta V_{OS}$		0	3	25	mV
Power-off Leakage	$I_{OXD}$	$V_{out} = V_{DD}$ or GND $V_{DD} = 0V$		$\pm 1$	$\pm 10$	$\mu A$
Output Short Circuit Current	$I_{OSD}$			-5.7	-8	mA

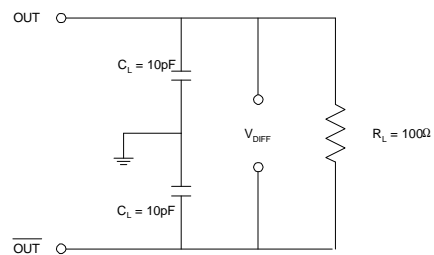
**8. LVDS Switching Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	$t_r$	$R_L = 100 \Omega$ $C_L = 10 \text{ pF}$ (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	$t_f$		0.2	0.7	1.0	ns

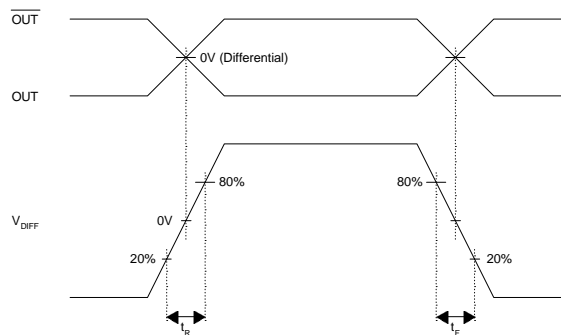
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transition Time Waveform



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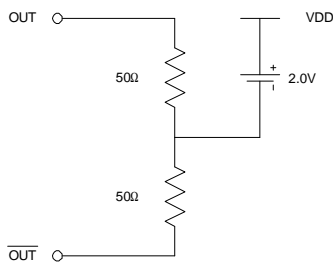
**9. PECL Electrical Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Output High Voltage	$V_{OH}$	$R_L = 50 \Omega$ to $(V_{DD} - 2V)$ (see figure)	$V_{DD} - 1.025$		V
Output Low Voltage	$V_{OL}$			$V_{DD} - 1.620$	V

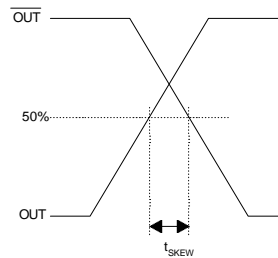
**10. PECL Switching Characteristics**

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	$t_r$	@20/80% - PECL		0.6	1.5	ns
Clock Fall Time	$t_f$	@80/20% - PECL		0.5	1.5	ns

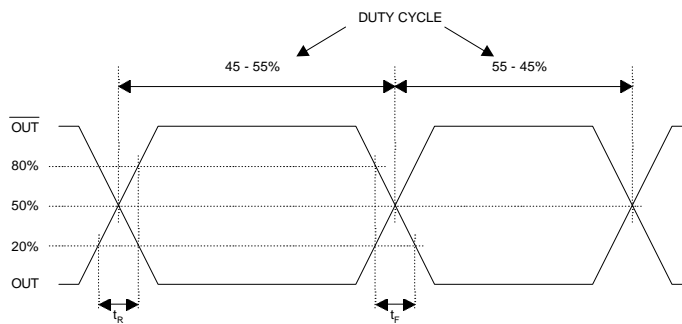
PECL Levels Test Circuit



PECL Output Skew



PECL Transition Time Waveform



**PECL and LVDS Low Phase Noise VCXO (for 65-130MHz Fund Xtal)**
**PAD ASSIGNMENT**

Pad #	Name	X (μm)	Y (μm)
1	<i>Optional GND</i>	248	109
2	<i>Optional GND</i>	361	109
3	<i>Optional GND</i>	473	109
4	<i>Optional GND</i>	587	109
5	GND	702	109
6	<i>Reserved</i>	874	109
7	<i>Optional GNDBUF</i>	1042	109
8	GNDBUF	1171	109
9	OUTSEL	1400	125
10	LVDS	1400	259
11	PECL	1400	476
12	VDDBUF	1400	616
13	<i>Optional VDDBUF</i>	1400	716
14	PECLB	1400	871
15	LVDSB	1400	1089
16	<i>Not connected</i>	1400	1227
17	GNDBUF	1389	1365
18	<i>Reserved</i>	1232	1365
19	<i>Reserved</i>	1042	1365
20	<i>Not connected</i>	854	1365
21	<i>Optional VDD</i>	659	1365
22	<i>Optional VDD</i>	559	1365
23	VDD	459	1365
24	<i>Optional VDD</i>	358	1365
25	<i>Not connected</i>	194	1365
26	XIN	109	1223
27	XOUT	109	1017
28	<i>Not connected</i>	109	858
29	<i>Not connected</i>	109	646
30	OE_CTRL	109	397
31	VCON	109	181

Note: for optimal Phase Noise performance, it is recommended to bond all optional VDD and GND pads.

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**ORDERING INFORMATION**

*For part ordering, please contact our Sales Department:*

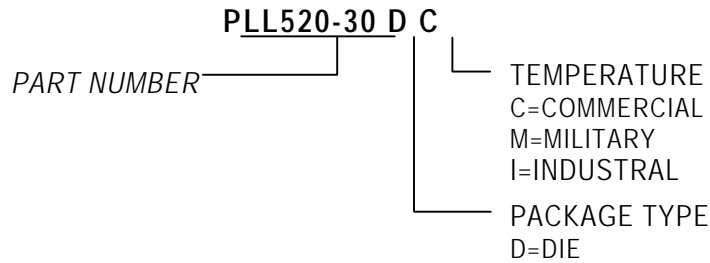
47745 Fremont Blvd., Fremont, CA 94538, USA

Tel: (510) 492-0990 Fax: (510) 492-0991

**PART NUMBER**

The order number for this device is a combination of the following:

Device number, Package type and Operating temperature range



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